

DEPARTMENT OF PHYSICS

	COURSE PLA	N – PART I		
Name of the programme and specialization	II Semester – M.Tech.	NDT		
Course Title	Electrical, Magnetic and Optoelectronic Materials			
Course Code	PH618	3		
Course Code of Pre- requisite subject(s)	NIL			
Session	January. 2019	Section (if, applicable)	NIL	
Name of Faculty	Dr. M. Dhavamurthy	Department	Physics	
Official Email	dhavam@nitt.edu	Telephone No.	NIL	
Name of Course Coordinator(s) (if, applicable)	Dr. B. Karthikeyan			
Official E-mail	bkarthik@nitt.edu	Telephone No.	0431-250-3616	
Course Type (please tick appropriately)	Core course	Elective co	ourse	

Syllabus (approved in BoS)

Electrical and Dielectric Materials

Review of electrical conduction – discussion on specific materials used as conductors (OFHC, Ag, Al, other alloys) – temperature dependent resistivity of Copper and CuNi alloy – Nordheim rule – CuAu alloy – dielectric phenomena – concept of polarization – effects of composition, frequency and temperature on these properties – discussion on specific materials used as dielectrics (ceramics and polymers) – BaTiO3 – dielectric loss, dielectric breakdown – ferro electricity – piezo and pyro electricity.

Magnetic Materials

Introduction to dia, para, ferri and ferro magnetism – hard and soft magnetic materials – ironsilicon alloys – iron, nickel alloys – ferrites, garnets and LCMO – rare earth alloys – Pt alloys – fine particle magnetism – applications of hard and soft magnetic materials – Giant Magneto Resistance – magnetocaloric effect – spintronics – multiferroics – nanomagnetic materials.

Superconducting and Semiconducting

Materials Concept of super conductivity – theories and examples for high temperature superconductivity – discussion on specific super conducting materials – Nb3Sn – YBCO – MgB2 – Carbon based – comments on fabrication and engineering applications – review of semiconducting materials – concept of doping – simple and compound semiconductors – amorphous semiconductor – oxide semiconductors – organic semiconductor – low dimensional semiconductor – materials for solar cell applications – Hall effect – homojunction – schottky barrier – heterojunction – materials and applications.



Production of Electronic Materials

Binary alloy phase diagram (PbSn and CuNi) – homogeneous and heterogeneous nucleation – methods of crystal growth for bulk single crystals – Czochralski – Bridgman – low and high temperature solution growth – floating zone method - synthesis of epitaxial films by LPE, VPE, PVD, MBE and MOCVD techniques – lithography – production of silicon – applications.

Optical and Optoelectronic Materials

Principles of photoconductivity – simple models – effect of impurities – principles of luminescence – types and materials, Laser Principles – ruby, He-Ne, injection, Nd-YAG and Dye lasers – LED materials – binary, ternary photo electronic materials – Optical storage materials – LCD materials – photo detectors – applications of optoelectronic materials – introduction to optical fibers – light propagation – electro optic effect – electro optic modulators – Kerr effect – Pockel's effect.

COURSE OBJECTIVES

- To review physics and chemistry in the context of materials science & engineering.
- To understand the fundamentals and applications of electrical, magnetic and optical properties of materials.
- Give an introduction to the relation between processing, structure, and physical properties.
- Apply a multi-disciplinary approach to plan, design, identify and address future needs of all the conventional and novel materials utilizing their properties for the society.
- Give the beginning student an appreciation of recent developments in materials science & engineering within the framework of this class.
- Give the beginning student an opportunity for teamwork in research.

MAPPING OF COs with POs				
Course Outcomes		Programme Outcomes (PO) (Enter Numbers only)		
1.	Given a type of electrical and dielectric materials, be able to qualitatively describe their general physical properties, as well as possible applications.	P1, P4, P6		
2.	Gain an introduction to the electronic, magnetic properties of bulk and nano-structured materials. Conceptually explain the classification of magnetic materials that are used to categorize engineering materials.	P1, P4, P6		
3.	To develop an understanding of the unique properties and characteristics of magnetic materials.	P1, P3, P9, P10		
4.	Obtain experience in performing in-depth research into a topic in electronic materials and summarizing their findings in written and oral reports.	P1, P4, P6, P7		
5.	Learn the fundamental properties of materials science that will serve as a foundation to understanding the electrical and optical properties of optoelectronic materials.	P1, P4, P6		



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Mar.2019

NATIONAL INSTITUTE OF TECHNOLOGY, TIRUCHIRAPPALLI

COURSE PLAN – PART II **COURSE OVERVIEW** The Physics- II course (Code: PH-IR12) is offered in the second semester to all the branches of engineering. The subject has 3 credit theory and 1 credit lab weightage. COURSE TEACHING AND LEARNING ACTIVITIES (Add more rows) S.No. Week/Contact Topic Mode of Delivery Hours Review of electrical conduction discussion on specific materials used 14-19 1 as conductors (OFHC, Ag, Al, other Chalk & Talk, CD Jan.2019 alloys) - temperature dependent resistivity of Copper and CuNi alloy. Nordheim rule- CuAu alloy-dielectric phenomena – concept of polarization 21-25 Chalk & Talk, CD, 2 Jan.2019 - effects of composition, frequency PPT and temperature on these properties Discussion on specific materials used as dielectrics - BaTiO3 - dielectric 28-01 Chalk & Talk, CD, loss, dielectric breakdown- ferro-3 Jan.- Feb.2019 PPT electricity - piezo and pyro electricity. Introduction to dia, para, ferri and ferro magnetism - hard and soft 04-08 Chalk & Talk, CD, 4 magnetic materials - ironsilicon Feb.2019 PPT alloys - iron, nickel alloys - ferrites, garnets and LCMO Rare earth alloys - Pt alloys - fine Chalk & Talk, CD, 11-15 5 particle magnetism - applications of PPT Feb.2019 hard and soft magnetic materials. Giant Magneto Resistance 18-22 Chalk & Talk, CD, magneto-caloric effect - spintronics -6 Feb.2019 PPT multiferroics-nanomagnetic materials. Materials Concept of super conductivity – theories and examples for high temperature 25-01 superconductivity - discussion on Chalk & Talk, CD, 7 specific super conducting materials -PPT Feb.-Mar.2019 Nb3Sn – YBCO – MgB2 – Carbon based – comments on fabrication and engineering applications. Review of semiconducting materials - concept of doping - simple and 04-08 compound semiconductors -Chalk & Talk, CD,

amorphous semiconductor - oxide

semiconductors - organic

semiconductor.

PPT



11-15 Mar.2019	barrier – heterojunction – materials and applications.			nalk & Talk, CD, PPT		
18-22 Mar.2019	Binary alloy phase diagram (PbSn			nalk & Talk, CD, PPT		
25-29 Mar.2019	Czochralski – Bridgman - Iow and high temperature solution growth – C floating zone method			Cł	halk & Talk, CD	
01-05 Apr.2019	Synthesis of epitaxial films by LPE, VPE, PVD, MBE and MOCVD Ch techniques - lithography - production of silicon - applications.			nalk & Talk, CD, PPT		
08-12 Apr.2019	Principles of photoconductivity – simple models – effect of impurities – principles of luminescence – types and materials,			halk & Talk, CD		
15-19 Apr.2019	Laser Principles – ruby, He-Ne,			Ch	halk & Talk, CD, PPT	
22-26 Apr.2019	photo detectors – applications of optoelectronic materials – introduction to optical fibers – lightCh Ch propagation electro optic effect – electro optic modulators – Kerr effect			alk & Talk, CD, PPT		
E ASSESSMENT MET	HODS (s	hall range from 4 to	6)			
Mode of Assessm	ent	Week/Date	Duratio	on	% Weightage	
Cyclic Test - I		Feb. 2 nd Week	60 mii	n	20	
Quiz/Seminar		Mar. 1 st Week	30 min		10	
Cyclic Test - II		Mar. 4 th Week	60 min		20	
Compensation Assessment		Apr. 2 nd Week	60 mii	n	20 (or) 10	
Final Assessment		Apr. 4 th Week	180 min		50	
Total Marrks					100	
	11-15 Mar.201918-22 Mar.201925-29 Mar.201901-05 Apr.201908-12 Apr.201915-19 Apr.201922-26 Apr.201932-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 Apr.201933-30 	11-15 Mar.2019Low dia material Hall effe barrier - and app18-22 Mar.2019Binary a and CuM heteroge of crysta crystals.25-29 Mar.2019Czochra high tem floating01-05 Apr.2019VPE, PV techniqu of silicor08-12 Apr.2019Principle and mat Laser Pri injection LED ma electron material photo de optoelect22-26 Apr.2019photo de optoelect introduc propaga electron c - PockeSSSESSMENT METHODS (sMode of Assessment Cyclic Test - IICyclic Test - IICompensation AssessmentFinal Assessment	11-15 Mar.2019Low dimensional semicor materials for solar cell app Hall effect – homojunction – and applications.18-22 Mar.2019Binary alloy phase diagram and CuNi) – homogeneous heterogeneous nucleation – of crystal growth for bulk sir crystals.25-29 Mar.2019Czochralski – Bridgman - Io high temperature solution g floating zone method01-05 Apr.2019Synthesis of epitaxial films I VPE, PVD, MBE and MOCV techniques - lithography - p of silicon - applications.08-12 Apr.2019Principles of photoconductiv simple models – effect of in principles of luminescence - and materials,15-19 Apr.2019Laser Principles – ruby, He injection, Nd-YAG and Dye LED materials – binary, terr electronic materials – Optic materials.22-26 Apr.2019photo detectors – applicatio optoelectronic materials – optic materials.22-26 Apr.2019photo detectors – application optoelectronic materials – binary, terr electro optic effectE ASSESSMENT METHODS (shall range from 4 toMode of AssessmentWeek/DateCyclic Test - IFeb. 2 nd WeekQuiz/SeminarMar. 4 th WeekCompensation AssessmentApr. 2 nd WeekFinal AssessmentApr. 4 th Week	11-15 Mar.2019Low dimensional semiconductor - materials for solar cell applications - Hall effect - homojunction - schottky barrier - heterojunction - materials and applications.18-22 Mar.2019Binary alloy phase diagram (PbSn and CuNi) - homogeneous and heterogeneous nucleation - methods of crystal growth for bulk single crystals.25-29 Mar.2019Czochralski - Bridgman - low and high temperature solution growth - floating zone method01-05 Apr.2019Synthesis of epitaxial films by LPE, VPE, PVD, MBE and MOCVD techniques - lithography - production of silicon - applications.08-12 Apr.2019Principles of photoconductivity - simple models - effect of impurities - principles of photoconductivity - simple models - effect of impurities - principles of luminescence - types and materials.15-19 Apr.2019Laser Principles - ruby, He-Ne, injection, Nd-YAG and Dye lasers. LED materials - binary, ternary photo electronic materials - introduction to optical storage materials.22-26 Apr.2019photo detectors - applications of optoelectronic materials - introduction to optical fibers - light propagation electro optic effect - electro optic effect - electro optic modulators - Kerr effectE ASSESSMENT METHODS (shall range from 4 to 6)Mode of AssessmentWeek/DateQuiz/SeminarMar. 1 st WeekQuiz/SeminarMar. 4 th WeekCompensation AssessmentApr. 2 nd WeekApr. 2 nd Week60 mi	11-15 Mar.2019 Low dimensional semiconductor – materials for solar cell applications – Hall effect – homojunction – schottky barrier – heterojunction – materials and applications. Ch 18-22 Mar.2019 Binary alloy phase diagram (PbSn and CuNi) – homogeneous and heterogeneous nucleation – methods of crystal growth for bulk single crystals. Ch 25-29 Mar.2019 Czochralski – Bridgman - low and high temperature solution growth – floating zone method Ch 01-05 Apr.2019 Synthesis of epitaxial films by LPE, VPE, PVD, MBE and MOCVD Ch 08-12 Apr.2019 Synthesis of epitaxial films by LPE, vinciples of photoconductivity – simple models – effect of impurities – principles of luminescence – types and materials, Ch 15-19 Apr.2019 Laser Principles – ruby, He-Ne, injection, Nd-YAG and Dye lasers. LED materials – Dinary, ternary photo electronic materials – Optical storage materials. Ch 22-26 Apr.2019 photo detectors – applications of optoelectronic materials – introduction to optical fibers – light propagation electro optic modulators – Kerr effect – Pockel's effect Ch EASESSMENT METHODS (shall range from 4 to 6) Mode of Assessment Week/Date Duration Quiz/Seminar Mar. 1 st Week 60 min Cyclic Test - I Feb. 2 nd Week 60 min Cyclic Test - II Mar. 4 th Week 60 min Final Assessment Apr. 4 th Week 60 min	



COURSE EXIT SURVEY (mention the ways in which the feedback about the course shall be assessed)

- > Asking summary of each class at the end of class.
- > Performance in the assessment methods.
- Questionnaire about the effectiveness of the delivery method, topics and the knowledge gained.

COURSE POLICY (including compensation assessment to be specified) MODE OF CORRESPONDENCE (email/ phone etc)

Both e-mail and phone

COMPENSATION ASSESSMENT POLICY

It is a test with duration of 60 min. Appropriate weightage (20 or 10) will be calculated.
ATTENDANCE POLICY (A uniform attendance policy as specified below shall be followed)

- > At least 75% attendance in each course is mandatory.
- > A maximum of 10% shall be allowed under On Duty (OD) category.
- Students with less than 65% of attendance shall be prevented from writing the final assessment and shall be awarded 'V' grade.

ACADEMIC DISHONESTY & PLAGIARISM

- Possessing a mobile phone, carrying bits of paper, talking to other students, copying from others during an assessment will be treated as punishable dishonesty.
- Zero mark to be awarded for the offenders. For copying from another student, both students get the same penalty of zero mark.
- The departmental disciplinary committee including the course faculty member, PAC chairperson and the HoD, as members shall verify the facts of the malpractice and award the punishment if the student is found guilty. The report shall be submitted to the Academic office.
- The above policy against academic dishonesty shall be applicable for all the programmes.

ADDITIONAL INFORMATION, IF ANY

ESSENTIAL READINGS : Textbooks, reference books, website addresses, journals, etc

- 1. C. Kittel, Introduction to Solid State Physics, John Wiley and Sons, 7th edition, New Delhi, (2004).
- 2. A. J. Dekker, Electrical Engineering Materials, Prentice Hall, NJ, (1959).
- 3. L. H. Van Vlack, Elements of Materials Science and Engineering, Addison Wesley, 6th edition, New York, (1989)
- 4. V. Raghavan, Materials Science and Engineering, Prentice Hall of India, 5th edition, New Delhi, (2013).



- 5. B. G. Yacobi, Semiconductor Materials: An Introduction to Basic Principles, Springer, 1st edition, New York, (2013).
- 6. S. Kasap and P. Capper (eds.), Handbook of Electronic and Photonic Materials, Springer, New York, (2007).
- 7. Ed. Charles P. Poole, Jr., Handbook of Superconductivity, Academic Press (2000).
- 8. Nicola. A. Spaldin, Magnetic Materials: Fundamentals and Applications, 2nd Edn., Cambridge Univ. Press. (2002)

Websites:

- 1. www.doitpoms.ac.uk/tlplib/dielectrics/index.php
- 2. nptel.ac.in/course.php

FOR APPROVAL

Course Faculty	CC- Chairperson		HOD
(DS)	-	(DS)	(DS)



<u>Guidelines</u>

- a) The number of assessments for any theory course shall range from 4 to 6.
- b) Every theory course shall have a final assessment on the entire syllabus with at least 30% weightage.
- c) One compensation assessment for absentees in assessments (other than final assessment) is mandatory. Only genuine cases of absence shall be considered.
- d) The passing minimum shall be as per the regulations.

B.Tech. Admitted in				P.G.
2018	2017	2016	2015	
35% or (Class average/2) whichever is greater.		(Peak/3) or (Class Average/2) whichever is lower		40%

- e) Attendance policy and the policy on academic dishonesty & plagiarism by students are uniform for all the courses.
- f) Absolute grading policy shall be incorporated if the number of students per course is less than 10.
- g) Necessary care shall be taken to ensure that the course plan is reasonable and is objective.